Resonant peak in the density of states in normal-metal/diffusive-ferromagnet/superconductor junctions

T. Yokoyama,1 Y. Tanaka,1 and A. A. Golubov2
1Department of Applied Physics, Nagoya University, Nagoya, 464-8603, Japan
and CREST, Japan Science and Technology Corporation Nagoya, 464-8603, Japan
2Faculty of Science and Technology, University of Twente, 7500 AE, Enschede, The Netherlands

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The conditions for the formation of zero-energy peak in the density of states (DOS) in the normal metal/insulator/diffusive ferromagnet/insulator/s-wave superconductor (N/I/DF/I/S) junctions are studied by solving the Usadel equations. The DOS of the diffusive-ferromagnet conductor (DF) is calculated in various regimes for different magnitudes of the resistance, Thouless energy, and the exchange field of the DF, as well as for various resistances of the insulating barriers. The conditions for the DOS peak are formulated for the cases of weak proximity effect [large resistance of the diffusive-ferromagnet/superconductor (DF/S) interface] and strong proximity effect (small resistance of the DF/S interface).

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In ferromagnet/superconductor (F/S) junctions, Cooper pairs penetrating into the F layer from the S layer have a nonzero momentum due to the influence of exchange field.1–3 This results in oscillating behavior of the pair amplitude or a π-phase shift of the order parameter in the ferromagnet. A negative sign of the real part of the order parameter may occur when the thickness of the F layer is larger than the coherence length of the F layer. The occurrence of the π-phase shift makes it possible to realize the SFS π junctions,1 as was confirmed experimentally.4–8 The order parameter oscillations also lead to nonmonotonous dependence of the transmission probability on the Fermi level for the case of tunneling through the superconductor/ferromagnet/superconductor (SFS) junctions.9–13 The parameter oscillations also lead to nonmonotonous dependence of the transmission probability on the Fermi level for the case of tunneling through the superconductor/ferromagnet/superconductor (SFS) junctions.9–13 The parameter oscillations also lead to nonmonotonous dependence of the transmission probability on the Fermi level for the case of tunneling through the superconductor/ferromagnet/superconductor (SFS) junctions.9–13

Another interesting consequence of the oscillations of the pair amplitude is the spatially damped oscillating behavior of the density of states (DOS) in a ferromagnet predicted theoretically17–20 in various regimes. The energy-dependent DOS calculated in the clean18 and the dirty21 limits exhibits rich structures. Experimentally DOS in F/S bilayers was measured by Kontos et al. who found a broad DOS peak around zero energy when the π-phase shift occurs.22 In diffusive-ferromagnet/superconductor (DF/S) junctions the zero-energy DOS may have a sharp peak.21 However, the conditions for the appearance of such an anomaly have not been studied systematically so far.

The purpose of the present paper is to calculate DOS in N/DF/S junctions and to formulate the conditions for the zero-energy DOS peak in two regimes corresponding to the weak proximity effect (large DF/S interface resistance) and strong proximity effect (small DF/S interface resistance). We will show that in the former case the condition is equivalent to the one of Ref. 21, while in the latter case the new condition is found. The calculation will be performed in the zero-temperature regime by varying the interface resistances as well as the resistance, the exchange field, and the Thouless energy of the DF layer.

We consider a junction consisting of normal and superconducting reservoirs connected by a quasi-one-dimensional diffusive-ferromagnet conductor (DF) with a resistance $R_d$ and a length $L$ much larger than the mean free path. The DF/N interface located at $x=0$ has the resistance $R'_n$, while the DF/S interface located at $x=L$ has the resistance $R_b$. We model infinitely narrow insulating barriers by the δ function $U(x)=\delta(x-L)+\delta'(x)$. The resulting transparencies of the junctions $T_m$ and $T'_m$ are given by $T_m=4\cos^2\phi/(4\cos^2\phi+Z^2)$ and $T'_m=4\cos^2\phi/(4\cos^2\phi+Z'^2)$, where $Z=2H/v_F$ and $Z'=2H'/v_F$ are dimensionless constants, $\phi$ is the injection angle measured from the interface normal to the junction, and $v_F$ is Fermi velocity.

In the following calculation we will apply the quasiclassical Green’s functions formalism. The $2 \times 2$ retarded Green’s functions in N, DF, and S are denoted by $\tilde{R}_0(x)$, $\tilde{R}_1(x)$, and $\tilde{R}_2(x)$ respectively. $\tilde{R}_0(x)$ and $\tilde{R}_2(x)$ are expressed by $\tilde{R}_0(x)=\tilde{\tau}_1$ and $\tilde{R}_2(x)=(g\tilde{\tau}_1+f\tilde{\tau}_2)$ respectively, with $g=\cos(\theta(x)),$ $f=\sin(\theta(x))$, and $e$ denote the energy gap and the quasiparticle energy measured from the Fermi energy, respectively. It is convenient to use the standard $\theta$ parametrization when function $\tilde{R}_1(x)$ is expressed as $\tilde{R}_1(x) = \tilde{\tau}_1 \cos(\theta(x)) + \tilde{\tau}_2 \sin(\theta(x))$. The parameter $\theta(x)$ is a measure of the proximity effect in DF. The spatial dependence of $\theta(x)$ in DF is determined by the static Usadel equation

$$D\frac{\partial^2}{\partial x^2} \theta(x) + 2i(e - (\pm)h)\sin[\theta(x)] = 0 \quad (1)$$

for majority (minority) spin with the diffusion constant $D$ and the exchange field $h$ in DF. Note that we assume a weak ferromagnet and neglect the difference of the Fermi velocities of the majority and minority spin subbands.

Further we shall apply the Nazarov’s boundary condition24 for $\theta(x)$ at both interfaces. At the DF/N interface it has the following form:

$$\tilde{R}_0(x) = \tilde{\tau}_1 \quad \text{for} \quad x = 0$$

and $\tilde{R}_2(x) = \tilde{\tau}_1 \quad \text{for} \quad x = L$.
and it has a similar form at the DF/S interface. This boundary condition is based on the Zaitsev’s boundary condition\textsuperscript{26} with isotropic limit and generalizes the Kupriyanov-Lukichev boundary condition.\textsuperscript{27}

The average over the various angles of injected particles at the interface is defined as

$$\langle B(\phi) \rangle' = \frac{\int_{-\pi/2}^{\pi/2} d\phi \cos \phi B(\phi)}{\int_{-\pi/2}^{\pi/2} d\phi},$$

with $B(\phi)=B$ and $T'(\phi)=T_m$. The resistance of the interface $R_b^{(i)}$ is given by

$$R_b^{(i)} = \frac{2}{\int_{-\pi/2}^{\pi/2} d\phi T'(\phi) \cos \phi}.$$

Here, for example, $R_b^{(1)}$ denotes $R_b$ or $R'_b$, and $R_0^{(1)}$ is Sharvin resistance, which in three-dimensional case is given by $R_0^{(1)}=\frac{2\hbar k_F^2 S_T}{(4\pi^2)}$, where $k_F$ is the Fermi wave vector and $S_T$ is the constriction area.

In the following, we will study the local DOS $N$ in the DF layer which is given by

$$\frac{N}{N_0} = \frac{1}{2} \sum_{\uparrow \downarrow} \text{Re} \cos \theta(x),$$

where $N_0$ denotes the DOS in the normal state. The DOS will be calculated by numerical solution of the Usadel equations with the boundary conditions given above.

Below we will concentrate on the DOS at $x=0$ (N/DF interface) in the regime of large resistance of the N/DF interface, $R_d/R_b' \ll 1$, and will also fix the barrier transparency parameters $Z=3, Z' = 3$.

In order to study the condition for the appearance of the zero-energy DOS peak, we plot the normalized zero-energy DOS at $x=0$ as a function of $E_{Th}=D/L^2$. Figure 1 shows the DOS for $R_d/R_b'=0.1$ and various $h/\Delta$. In Fig. 1(a) the zero-energy peak appears at $E_{Th\approx 2hR_b}$, while in Fig. 1(b) and 1(c) the peak appears at $E_{Th\sim h}$. Thus we can conclude that the condition for the DOS peak for large $R_d/R_b$ is essentially different from the one for small $R_d/R_b$.

Figure 2 shows the DOS as a function of $\varepsilon$ for the parameters corresponding to the peaks in Fig. 1 for various $h/\Delta$. In all these cases the DOS peak appears around zero energy. For small $h/\Delta$ the DOS peak is narrow but it becomes broader with the increase of $h/\Delta$. It’s important to note that this peak does not always require the sign change of pair amplitude. This is also clear from the fact that the peak occurs for large Thouless energy (short DF) when there is no sign change.

FIG. 1. Normalized zero energy DOS as a function of $E_{Th}$ for large resistance of the N/DF interface $R_d/R_b'=0.1$ and various $h/\Delta$ with resistance ratios at the DF/S interface (a) $R_d/R_b=1$, (b) $R_d/R_b=5$, and (c) $R_d/R_b=10$.

FIG. 2. Normalized DOS as a function of $\varepsilon$ for $R_d/R_b'=0.1$ and various $h/\Delta$ with (a) $R_d/R_b=1$ and $E_{Th}=2hR_d/R_b=2h$, (b) $R_d/R_b=5$ and $E_{Th}=h$, and (c) $R_d/R_b=10$ and $E_{Th}=h$. 

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From Fig. 4, the magnitude of Im $\theta$ increases with increasing $R_d/R_b$, suggesting that peak at $E_{Th} = \Delta$ is suppressed with increasing $R_d/R_b$. Therefore, this condition is valid for small $R_d/R_b$.

Figure 4 shows the spatial dependence of Im $\theta$ for majority spin for $R_d/R_b = 0.1$, $E_{Th}/\Delta = 1$, and various $h/\Delta$ with (a) $R_d/R_b = 5$ and (b) $R_d/R_b = 10$. For the appearance of the DOS peak, large value of Im $\theta$ is needed because the normalized DOS is given by Re $\cos(\theta) = \cos(\Delta \cosh \theta) \cos(\text{Im}(\theta))$ as seen from Eq. 4. The magnitude of Im $\theta$ increases with the increase of the distance from the ferromagnet and achieves a maximum when $E_{Th} = h$.

Note that the zero-energy DOS at $x = 0$ does not depend on $E_{Th}$ if the condition $E_{Th} = h$ holds. To explain that, let’s write Eqs. (1) and (2) at $\epsilon = 0$:

$$\frac{d^2}{dy^2} \theta(y) - (-1)2i \sin[\theta(y)] = 0,$$

$$\frac{1}{R_d} \frac{\partial \theta(y)}{\partial y} \bigg|_{y=0} = \frac{E}{R'_b},$$

where $y = x/\sqrt{D/h}$. Since for $E_{Th} = h$ we have $D/h = E_{Th} L^2/h = L^2$, the above equations don’t contain $E_{Th}$ as a parameter. Similar arguments can be applied to another boundary condition at Df/S interface. This proves the above statement about independence of the zero-energy DOS at $x = 0$ on $E_{Th}$.

Now let us discuss the weak proximity effect and derive the condition $R_d/R_b \sim 2h/E_{Th}$, following Ref. 21. When spatial variation of $\theta$ is small, i.e., $L \ll \sqrt{D/|\epsilon + h|}$ (for the spin-up or spin-down subband respectively) and both $R_d/R_b$ and $R_d/R_b'$ are small (weak proximity effect), $\theta$ can be expanded as $\theta = \theta_0 + \theta_1 x + \theta_2 x^2$ where $\theta_1, \theta_2 \ll \theta_0$. Note that the derivatives of $\theta$ are proportional to these quantities at the interfaces [see Eq. (2) and Ref. 25].

In this case the solution of the Usadel equation in the spin-up subband satisfying boundary conditions has the form:

$$\cos \theta_{01} = \frac{2i(\epsilon - h)}{E_{Th}} \sqrt{\left(\frac{R_d}{R_b'}\right)^2 + \left(\frac{R_d}{R_b} + \frac{R_d}{R_b'}\right)^2 - \frac{2i(\epsilon - h)}{E_{Th}}} - \frac{2i(\epsilon - h)}{E_{Th}}.$$

For $R_d/R_b' = 0$ and $\epsilon = 0$, the DOS has the form

$$\cos \theta_{01} = \frac{2i\hbar}{E_{Th}}.$$

which provides the resonant condition $R_d/R_b \sim 2h/E_{Th}$. Similar result follows for the spin-down subband by replacing $h$ by $-h$.

Another resonant condition for the strong proximity effect, $E_{Th} \sim h$, is equivalent to the condition $L \sim \sqrt{D/h}$. Thus, zero-energy DOS peak appears when the proximity effect is strong and the length of ferromagnet is of the order of the coherence length in a ferromagnet $L \sim \sqrt{D/h}$.

Let us discuss the physical meaning of two conditions. In DN/S junctions there is a minigap $E_g$, where $E_g \sim E_{Th} R_d/R_b$.
for weak proximity effect, or $E_g \sim E_{Th}$ for strong proximity effect. In DF/S junctions this minigap is shifted by $h$, then the DOS peak appears when $h \sim E_g$.

Note that in the calculations we have fixed $Z = Z' = 3$, but the specific parameter choice does not change the results qualitatively.

In summary, we have studied the conditions for the appearance of the DOS peak in diffusive ferromagnet, in normal metal/diffusive ferromagnet/$s$-wave superconductor junctions. We have discussed two regimes of weak and strong proximity effect depending on the ratio $R_d/R_b$. The results in the regime of weak proximity effect are essentially the same as found in Ref. 21. However, in the regime of strong proximity effect the results are qualitatively different. Let us summarize the two conditions:

1. When the proximity effect is weak ($R_d/R_b \ll 1$), the condition for the DOS peak is $R_d/R_b \sim 2h/E_{Th}$.

2. When the proximity effect is strong ($R_d/R_b \gg 1$), the DOS peak appears when $E_{Th} \sim h$, i.e. when the length of ferromagnet is of the order of the coherence length $\sqrt{D/h}$.

Note that the above two conditions cross over into each other when $R_d/R_b \sim 2$. Since the DOS is a fundamental quantity affecting various physical properties, our results may have many applications, e.g., for the conductance of N/DF/S structures.

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